

FAST: [Untitled1:1]

File View Edit Tools Window Help

Pending

Active

Failed

Saved

Favorites

L4: (2) ("6677630").PN

L5: (3587) (438/3,238,239,250,386,393,399).CCLS

L6: (4153) (257/295,296,300).CCLS

L8: (2) "20020038402"

L7: (2) "20020000585"

L9: (11) (("6500677") or ("6121649") or ("5994153") or ("6458602") or ("62

L17: (2) 5 and pair near3 (contact adj plug)

L16: (1) 5 and buried near3 interconnect\$3 and pair near3 (contact adj plug)

L15: (3) 6 and buried near3 interconnect\$3 and pair near3 (contact adj plug)

L18: (5) 6 and pair near3 (contact adj plug)

L19: (12) 6 and ((pair two) near3 (contact adj plug))

L20: (6) 5 and ((pair two) near3 (contact adj plug))

DBs

USPAT:US:PGPUB,EPD,JPD:DE

Phosla

Default operator:

GR

Highlight all hit terms initially

5 and ((pair two) near3 (contact adj plug))

Actions

Actions

Group

View

Print

	U	I	Document ID	Issue Date	Pages	Title	Current	Cur Re	Inventor	S	C	P	2	3
1	<input type="checkbox"/>	<input type="checkbox"/>	US 20030234411 A1	20031225	14	SEMICONDUCTOR DE	257/295	257/	Kanaya, Hiroyuki et	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
2	<input type="checkbox"/>	<input type="checkbox"/>	US 20030042522 A1	20030306	27	Semiconductor memory	257/298	257/	Mikawa, Takumi et	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
3	<input type="checkbox"/>	<input type="checkbox"/>	US 20010022372 A1	20010920	63	Semiconductor device ha	257/295	257/	Kanaya, Hiroyuki et	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
4	<input type="checkbox"/>	<input type="checkbox"/>	US 6620672 B1	20030916	17	SOI DRAM with buried	438/239	438/	Dennison, Charles	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
5	<input type="checkbox"/>	<input type="checkbox"/>	US 6518120 B2	20030211	9	Capacitor and method of	438/244	257/	Park, Jong Bum	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
6	<input type="checkbox"/>	<input type="checkbox"/>	US 6190957 B1	20010220	43	Method of forming a ferr	438/240	257/	Mochizuki, Hiroshi	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>

Ready

NUM